# NSN 5962-01-312-4265

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-312-4265

0	1
Overall	Length:

0.960 inches

**Overall Height:** 

0.400 inches

## **Body Length:**

0.960 inches

#### Body Width:

Between 0.220 inches and 0.310 inches

#### **Body Height:**

Between 0.130 inches and 0.185 inches

## **Maximum Power Dissipation Rating:**

794.0 milliwatts

**Operating Tempurature Range:** 

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

3-state output and monolithic and bipolar and schottky and programmed and high impedance and w/enable

#### Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

12 input

## **Case Outline Source And Designator:**

D-6 mil-m-38510

## **Current Rating Per Characteristic:**

140.00 milliamperes reverse current, dc absolute

#### **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

## Time Rating Per Chacteristic:

85.00 nanoseconds access

# Memory Device Type:

Prom

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

16 printed circuit

# NSN 5962-01-312-4265

Memory Microcircuit - Page 2 of 2

Shelf Life:

N/a

Unit Of Measure:

---

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

